NSN 5961-01-368-9011

No Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-368-9011 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.675 inches **Overall Width:** Between 0.135 inches and 0.145 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-92 **Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 4.99 reverse breakdown voltage, dc and 5.01 reverse breakdown voltage, dc **Current Rating Per Characteristic:** 15.00 milliamperes collector current, dc peak and 10.00 milliamperes all primaries preset **Capacitance Rating In Picofarads:** 300.0 **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Item has a trim pin allowing additional output adjustment; junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:**